PC851XNNSZ1H Series

DIP 4pin High Collector-emitter Voltage Photocoupler



Description

PC851XNNSZ1H Series contains an IRED optically coupled to a phototransistor.

It is packaged in a 4-pin DIP, available in SMT gullwing lead-form option.

Input-output isolation voltage(rms) is 5.0kV. Collector-emitter voltage is 350V.

Features

- 1. 4pin DIP package
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. High collector-emitter voltage (V_{CEO}: 350V)
- 4. High isolation voltage between input and output $(V_{iso(rms)}: 5.0 \, kV)$
- 5. Lead-free and RoHS directive compliant

■ Agency approvals/Compliance

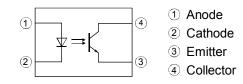
- 1. Recognized by UL1577, file No. E64380 (as model No. **PC851**)
- 2. Package resin : UL flammability grade (94V-0)

Applications

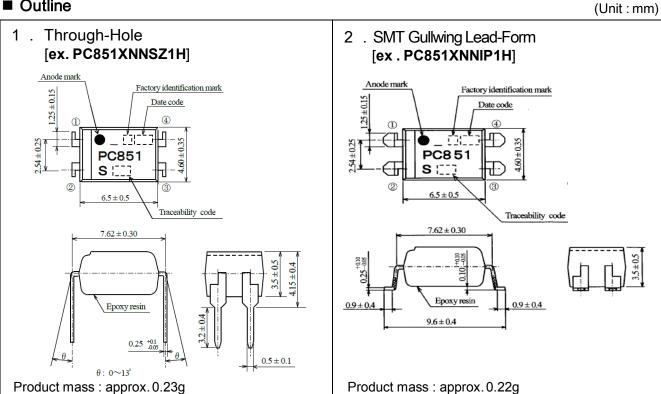
- 1. Telephone line interface/isolation
- 2. Interface to power supply circuit
- 3. Controller for SSRs, DC moters



Internal Connection Diagram



■ Outline



Date code indication (Ex.)

3-digit number shall be marked the age indication of 1-digit number, and week code of 2-digit number. Week code "01" indicate the week including the first Thursday of January. And later, Monday is the starting point.

Year	Week
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Date code	MON	TUE	WED	THU	FRI	SAT	SUN
652	12/26	12/27	12/28	12/29	12/30	12/31	1/1
701	1/2	1/3	1/4	1/5	1/6	1/7	1/8
702	1/9	1/10	1/11	1/12	1/13	1/14	1/15
703	1/16	1/17	1/18	1/19	1/20	1/21	1/22
•	•	•	•	•	•	•	•
•	•	•	•	•	•	•	•
•	•	•	•	•	•	•	•
752	12/11	12/12	12/13	12/14	12/15	12/16	12/17
751	12/18	12/19	12/20	12/21	12/22	12/23	12/24
752	12/25	12/26	12/27	12/28	12/29	12/30	12/31
801	1/1	1/2	1/3	1/4	1/5	1/6	1/7

Factory identification mark and Plating material

Factory identification Mark	Country of origin	Plating material
К	Japan	SnBi (Bi : 1~4%)

Rank mark

Refer to the Model Line-up table.

Absolute Maximum Ratings

■ ,	Absolute Maximum Ratings $(T_a=25^{\circ}C)$							
	Parameter	Symbol	Rating	Unit				
	Forward current	I_F	50	mA				
Input	*1 Peak forward current	I_{FM}	1	А				
Inf	Reverse voltage	Vr	6	V				
	Power dissipation	Р	70	mW				
	Collector-emittervoltage	V _{CEO}	350	V				
	Emitter-collector voltage	V _{ECO}	6	V				
Output	Collector current	I _C	50	mA				
	Collector power dissipation	Рс	150	mW				
Total power dissipation		P _{tot}	200	mW				
*2 Isolation voltage		V _{iso (rms)}	5	kV				
Operating temperature		T _{opr}	-25 to +100	°C				
5	Storage temperature	T _{stg}	-55 to +125	°C				
*3 Soldering temperature		T _{sol}	270	°C				

*1 Pulse width≤100µs, Duty ratio : 0.001 *2 40 to 60%RH, AC for 1 minute *3 For 10s

Electro-optical Characteristics

Elect	Electro-optical Characteristics (T _a =25°							
	Para	meter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
	Forward voltage		$V_{\rm F}$	I _F =20mA	—	1.2	1.4	V
Input	Reverse Cu	rrent	IR	V _R =4V	_	_	10	μΑ
	Terminal ca	pacitance	Ct	V=0, f=1kHz	_	30	250	pF
	Dark current		I _{CEO}	Vce=200V, If=0	—	—	1	μΑ
Output	Collector-emitter breakdown voltage		BV_{CEO}	$I_{C}=0.1mA, I_{F}=0$	350	-	-	V
	Emitter-collector breakdown voltage		$\mathrm{BV}_{\mathrm{ECO}}$	$I_E=10\mu A$, $I_F=0$	6	—	—	V
	Collector current		Ic	$I_F=5mA, V_{CE}=5V$	2.0	4.0	-	mA
	Collector-emitter saturation voltage		$V_{CE(sat)}$	IF=20mA, IC=1mA	_	0.1	0.3	V
Transfer	Isolation resistance		R _{ISO}	DC500V, 40 to 60%RH	5×1010	1×10 ¹¹	-	Ω
charac-	Floating capacitance		C_{f}	V=0, f=1MHz	_	0.6	1.0	pF
teristics	Cut-off frequency		\mathbf{f}_{C}	$V_{CE}=5V$, $I_C=2mA$, $R_L=100\Omega$, $-3dB$	_	50	-	kHz
	Response Rise time time Fall time		tr	$V_{0} = 2V I_{0} = 2mA P_{1} = 1000$	_	4	10	μs
			$t_{\rm f}$	$V_{CE}=2V, I_C=2mA, R_L=100\Omega$	_	5	12	μs

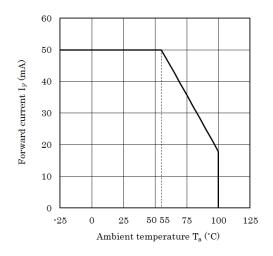


Model Line-up

Lead Form	Through-Hole	SMT Gullwing
Package	Sleeve	Taping
	100pcs/sleeve	2,000pcs/reel
Model No.	PC851XNNSZ1H	PC851XNNIP1H

Please contact a local SHARP sales representative to inquire about production status.

Fig.1 Forward Current vs. Ambient Temperature





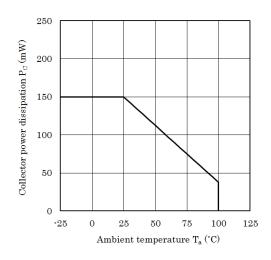


Fig.5 Peak Forward Current vs. Duty Ratio

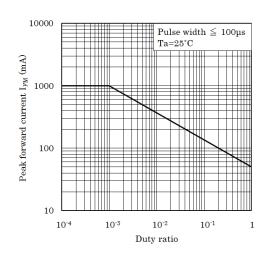


Fig.2 Diode Power Dissipation vs. Ambient Temperature

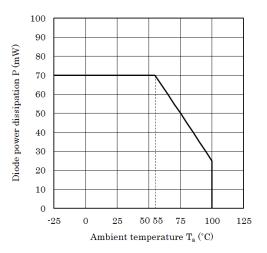


Fig.4 Total Power Dissipation vs. Ambient Temperature

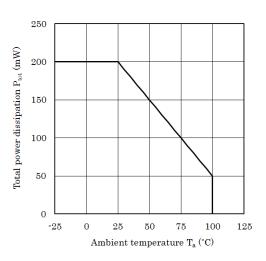


Fig.6 Forward Current vs. Forward Voltage

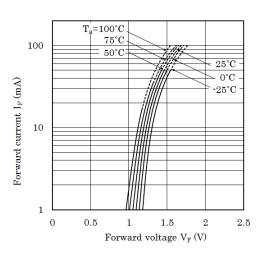


Fig.7 Current Transfer Ratio vs. Forward Current

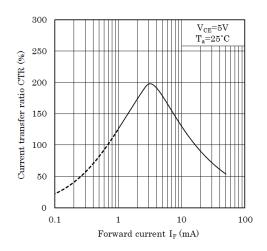


Fig.9 Relative Current Transfer Ratio vs. Ambient Temperature

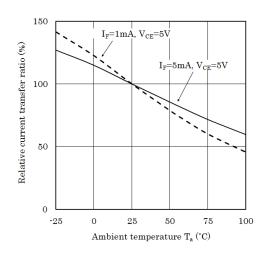


Fig.11 Collector Dark Current vs. Ambient Temperature

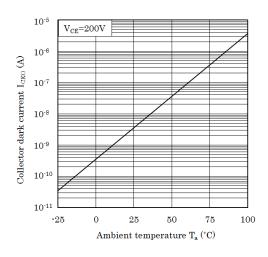


Fig.8 Collector Current vs. Collector-emitter Voltage

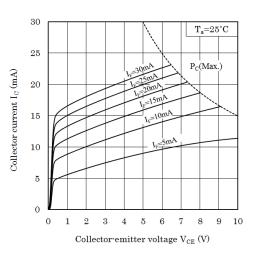


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

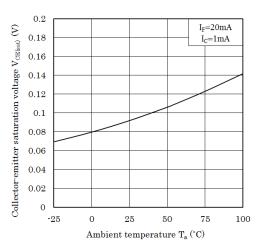


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current

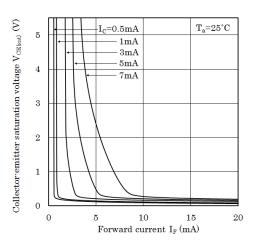
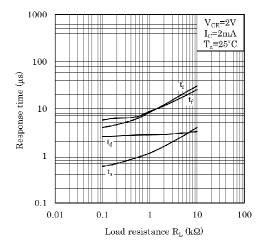




Fig.13 Response Time vs. Load Resistance



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Fig.14 Test Circuit for Response Time

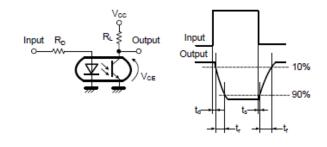


Fig.15 Frequency Response

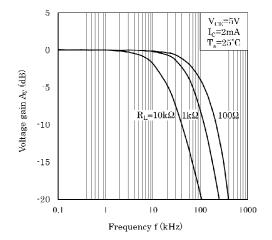
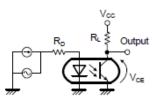


Fig.16 Test Circuit for Frequency Response



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.



Design Considerations

• Design guide

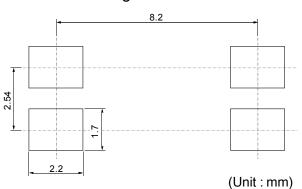
While operating at I_F <1mA, CTR variation may increase. Please make design considering this fact.

This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

In general, the emission of the IRED used in photocouplers will degrade over time. In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

• Recommended foot print (reference)



SMT Gullwing lead-form

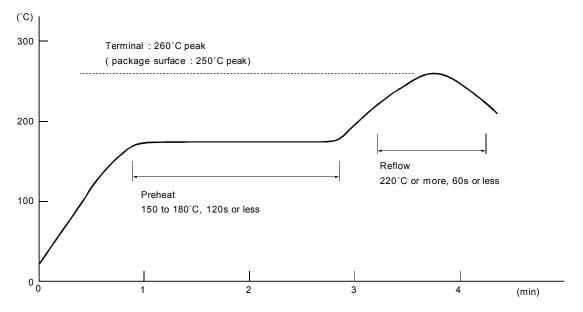
☆ For additional design assistance, please review our corresponding Optoelectronic Application Notes.

Manufacturing Guidelines

• Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below. Soldering should not exceed the curve of temperature profile and time. Please don't solder more than twice.



Flow Soldering :

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s. Preheating is within the bounds of 100 to 150°C and 30 to 80s. Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C. Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



• Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below. Immersion time should be 3 minutes or less.

Ultrasonic cleaning :

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials :

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol. In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

• Presence of ODC

This product shall not contain the following materials. And they are not used in the production process for this product. Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBB and PBDE are not used in this product at all.

- (1) The RoHS directive(2011/65/EU) This product complies with the RoHS directive(2011/65/EU) Object substances: mercury, lead, cadmium, hexavalent chromium, polybrominated biphenyls (PBB) and polybrominated diphenyl ethers (PBDE)
- (2) Content of six substances specified in Management Methods for Control of Pollution Caused by Electronic Information Products Regulation (Chinese: 电子信息产品污染控制管理办法).

	Hazardous Substances						
Category	Lead (Pb)	Mercury (Hg)	Cadmium (Cd)	Hexavalent chromium (Cr ⁶⁺)	Polybrominated biphenyls (PBB)	Polybrominated diphenyl ethers (PBDE)	
Photocoupler	0	0	0	0	0	0	

This table is prepared in accordance with the provisions of SJ/T 11364.

• : Indicates that said hazardous substance contained in all of the homogeneous materials

for this part is below the limit requirement of GB/T 26572.

Package specification

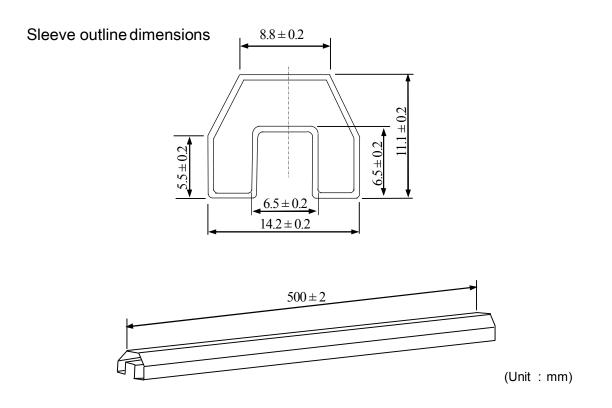
• Sleeve package Through-Hole

Package materials

Sleeve : HIPS/PS or PC (with anti-static material) Stopper : EPM

Package method

MAX. 100pcs. of products shall be packaged in a sleeve and both of sleeve edges shall be fixed by stoppers. MAX. 25 sleeves (Product : 2,500pcs.) above shall be packaged in inner case and sealed by tape . Max 2 bags(product : 5,000pcs) above shall be packaged in packing case , and put a cushioning material inside.





• Tape and Reel package

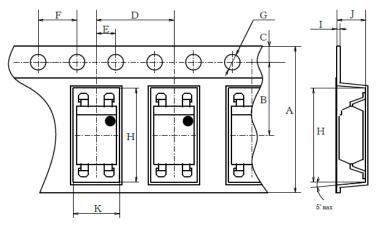
SMT Gullwing

Package materials

Carrier tape : PS

Cover tape : PET (three layer system) Reel : PS

Carrier tape structure and Dimensions



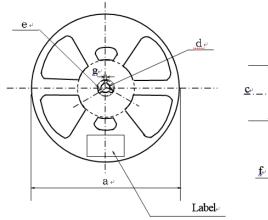
Dimensions List (Unit : mm)

А	В	С	D	Е	F	G
$16.0^{\pm0.3}$	7.5 ^{±0.1}	$1.75^{\pm 0.10}$	$8.0^{\pm 0.1}$	$2.0^{\pm0.1}$	$4.0^{\pm 0.1}$	$\phi 1.5^{+0.1}_{-0.0}$
Н	Ι	J	K			
$10.3^{\pm0.1}$	$0.40^{\pm0.05}$	$4.0^{\pm 0.1}$	$5.3^{\pm 0.1}$			

-

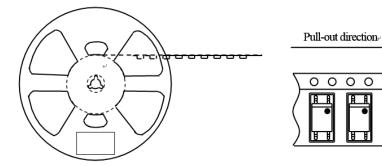
b₊

Reel structure and Dimensions



Dimensio	ns List	(U	nit : mm)
а	b	с	d
¢330	$17.5^{\pm 1.5}$	φ100 ^{±1}	\$13.0 ^{±0.5}
e	f	g	
$\phi 21.0^{\pm 1}$	$2.0^{\pm 0.5}$	2.0 ^{±0.5}	

Direction of product insertion



[Packing: 2,000pcs/reel]

0 0 C

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(i)The devices in this publication are designed for use in general electronic equipment designs such as:

- --- Personal computers
- --- Office automation equipment
- --- Telecommunication equipment [terminal]
- --- Test and measurement equipment
- --- Industrial control
- --- Audio visual equipment
- --- Consumer electronics

(ii)Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection with equipment that requires higher reliability such as:

- --- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

- --- Space applications
- --- Telecommunication equipment [trunk lines]
- --- Nuclear power control equipment
- --- Medical and other life support equipment (e.g., scuba).

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